COM'L: -10/12/15/20

IND: -14/18/24

Advanced Devices

MACH220-10/12/15/20

High-Density EE CMOS Programmable Logic

DISTINCTIVE CHARACTERISTICS

- 68 Pins
- 96 Macrocells
- 10 ns tpp
- 100 MHz fcnt
- 56 Inputs with pull-up resistors

- 48 Outputs
- 96 Flip-flops; 4 clock choices
- 8 "PAL26V12" blocks with buried macrocells
- Pin-compatible with MACH120 and MACH221

GENERAL DESCRIPTION

The MACH220 is a member of AMD's high-performance EE CMOS MACH 2 device family. This device has approximately nine times the logic macrocell capability of the popular PAL22V10 without loss of speed.

The MACH220 consists of eight PAL blocks interconnected by a programmable switch matrix. The eight PAL blocks are essentially "PAL26V12" structures complete with product-term arrays, and programmable macrocells, including buried macrocells. The switch matrix connects the PAL blocks to each other and to all input pins, providing a high degree of connectivity between the fully-connected PAL blocks. This allows designs to be placed and routed efficiently.

The MACH220 has two kinds of macrocell: output and buried. The output macrocell provides registered, latched, or combinatorial outputs with programmable

polarity. If a registered configuration is chosen, the register can be configured as D-type or T-type to help reduce the number of product terms. The register type decision can be made by the designer or by the software. All output macrocells can be connected to an I/O cell. If a buried macrocell is desired, the internal feedback path from the macrocell can be used, which frees up the I/O pin for use as an input.

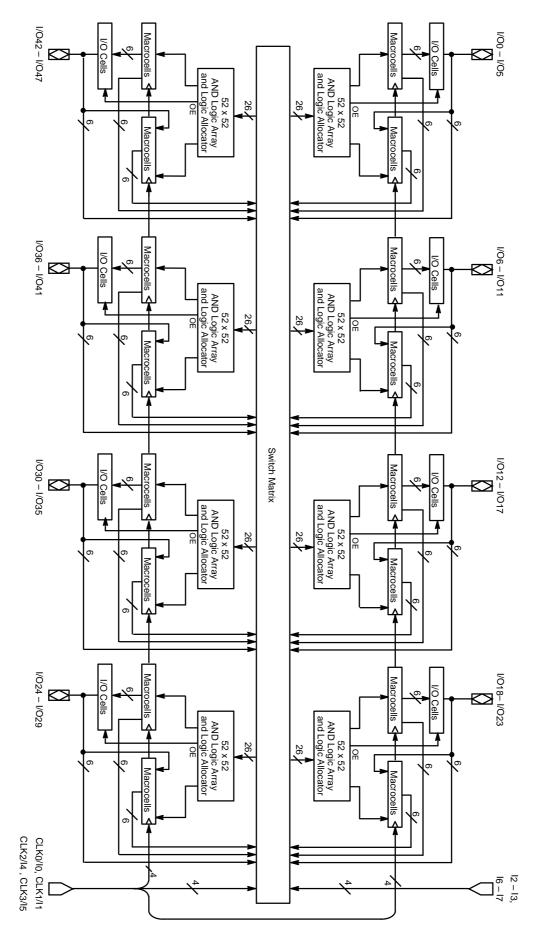
The MACH220 has dedicated buried macrocells which, in addition to the capabilities of the output macrocell, also provide input registers for use in synchronizing signals and reducing setup time requirements.

BLOCK DIAGRAM

If you would like to view Block Diagram in full size, please click on the box.

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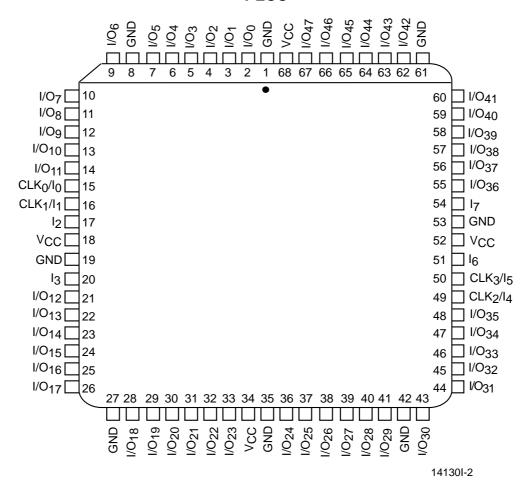


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CONNECTION DIAGRAMS

Top View





Note: Pin-compatible with MACH120 and MACH221.

PIN DESIGNATIONS

CLK/I = Clock or Input

GND = Ground

I = Input

I/O = Input/Output

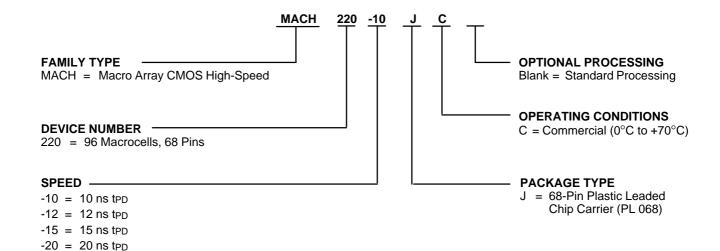
V_{CC} = Supply Voltage



ORDERING INFORMATION

Commercial Products

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid Combin	ations
MACH220-10	
MACH220-12	
MACH220-15	JC
MACH220-20	

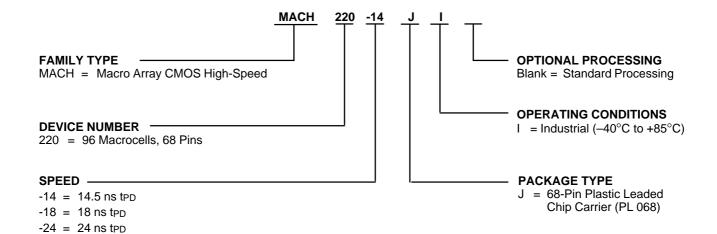
Valid Combinations

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

ORDERING INFORMATION

Industrial Products

AMD programmable logic products for industrial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid Combin	ations
MACH220-14	
MACH220-18	JI
MACH220-24	

Valid Combinations

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.



FUNCTIONAL DESCRIPTION

The MACH220 consists of eight PAL blocks connected by a switch matrix. There are 48 I/O pins and 4 dedicated input pins feeding the switch matrix. These signals are distributed to the four PAL blocks for efficient design implementation. There are 4 clock pins that can also be used as dedicated inputs.

All inputs and I/O pins have built-in pull-up resistors. While it is always good design practice to tie unused pins high or low, the pull-up resistors provide design security and stability in the event that unused pins are left disconnected.

The PAL Blocks

Each PAL block in the MACH220 (Figure 1) contains a 48-product-term logic array, a logic allocator, 6 output macrocells, 6 buried macrocells, and 6 I/O cells. The switch matrix feeds each PAL block with 26 inputs. This makes the PAL block look effectively like an independent "PAL26V12" with 6 buried macrocells.

In addition to the logic product terms, two output enable product terms, an asynchronous reset product term, and an asynchronous preset product term are provided. One of the two output enable product terms can be chosen within each I/O cell in the PAL block. All flip-flops within the PAL block are initialized together.

The Switch Matrix

The MACH220 switch matrix is fed by the inputs and feedback signals from the PAL blocks. Each PAL block provides 12 internal feedback signals and 6 I/O feedback signals. The switch matrix distributes these signals back to the PAL blocks in an efficient manner that also provides for high performance. The design software automatically configures the switch matrix when fitting a design into the device.

The Product-Term Array

The MACH220 product-term array consists of 48 product terms for logic use, and 4 special-purpose product terms. Two of the special-purpose product terms provide programmable output enable, one provides asynchronous reset, and one provides asynchronous preset.

The Logic Allocator

The logic allocator in the MACH220 takes the 48 logic product terms and allocates them to the 12 macrocells as needed. Each macrocell can be driven by up to 16 product terms. The design software automatically configures the logic allocator when fitting the design into the device.

Table 1 illustrates which product term clusters are available to each macrocell within a PAL block. Refer to Figure 1 for cluster and macrocell numbers.

Table 1. Logic Allocation

Масі	ocell	Available
Output	Buried	Clusters
M ₀		C ₀ , C ₁ , C ₂
	M ₁	C_0, C_1, C_2, C_3
M ₂		C ₁ , C ₂ , C ₃ , C ₄
	M ₃	C_2, C_3, C_4, C_5
M ₄		C ₃ , C ₄ , C ₅ , C ₆
	M_5	C_4, C_5, C_6, C_7
M ₆		C ₅ , C ₆ , C ₇ , C ₈
	M ₇	C ₆ , C ₇ , C ₈ , C ₉
M ₈		C ₇ , C ₈ , C ₉ , C ₁₀
	Мэ	C ₈ , C ₉ , C ₁₀ , C ₁₁
M ₁₀		C ₉ , C ₁₀ , C ₁₁
	M ₁₁	C ₁₀ , C ₁₁

The Macrocell

The MACH220 has two types of macrocell: output and buried. The output macrocells can be configured as either registered, latched, or combinatorial, with programmable polarity. The macrocell provides internal feedback whether configured with or without the flipflop. The registers can be configured as D-type or T-type, allowing for product-term optimization.

The flip-flops can individually select one of four clock/gate pins, which are also available as data inputs. The registers are clocked on the LOW-to-HIGH transition of the clock signal. The latch holds its data when the gate input is HIGH, and is transparent when the gate input is LOW. The flip-flops can also be asynchronously initialized with the common asynchronous reset and preset product terms.

The buried macrocells are the same as the output macrocells if they are used for generating logic. In that case, the only thing that distinguishes them from the output macrocells is the fact that there is no I/O cell connection, and the signal is only used internally. The buried macrocell can also be configured as an input register or latch.

The I/O Cell

The I/O cell in the MACH220 consists of a three-state output buffer. The three-state buffer can be configured in one of three ways: always enabled, always disabled, or controlled by a product term. If product term control is chosen, one of two product terms may be used to provide the control. The two product terms that are available are common to all I/O cells in a PAL block.

These choices make it possible to use the macrocell as an output, an input, a bidirectional pin, or a three-state output for use in driving a bus.

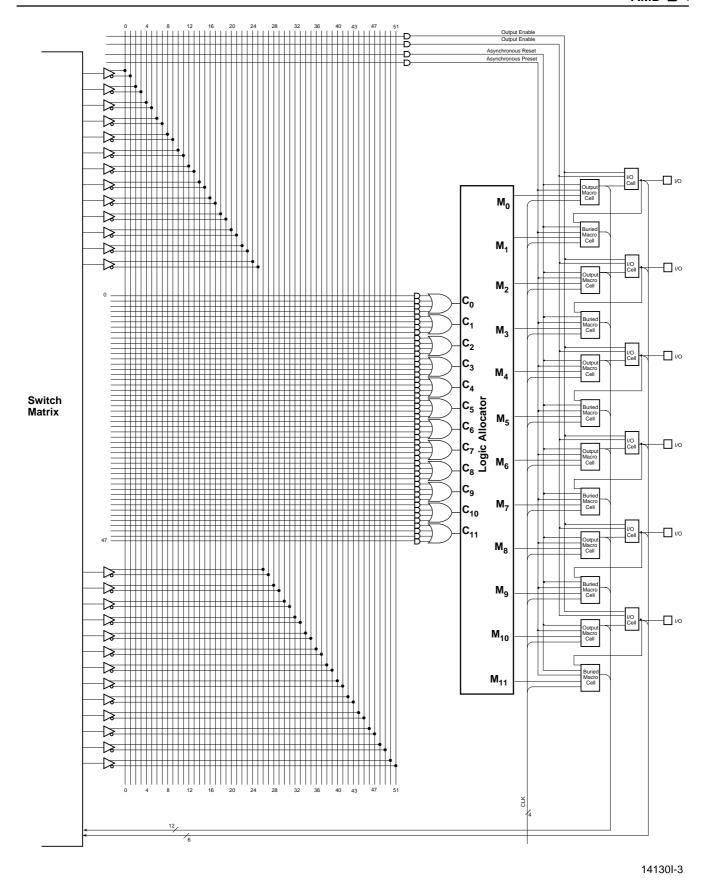


Figure 1. MACH220 PAL Block

MACH220-10/12/15/20



ABSOLUTE MAXIMUM RATINGS

Storage Temperature -65° C to $+150^{\circ}$ C Ambient Temperature with Power Applied -55° C to $+125^{\circ}$ C Supply Voltage with Respect to Ground -0.5 V to +7.0 V DC Input Voltage -0.5 V to V_{CC} + 0.5 V DC Output or I/O Pin Voltage -0.5 V to V_{CC} + 0.5 V Static Discharge Voltage 2001 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

Latchup Current ($T_A = 0^{\circ}C$ to $+70^{\circ}C$) 200 mA

OPERATING RANGES

Commercial (C) Devices

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Тур	Max	Unit
Vон	Output HIGH Voltage	$I_{OH} = -3.2$ mA, $V_{CC} = Min$ $V_{IN} = V_{IH}$ or V_{IL}	2.4			>
V_{OL}	Output LOW Voltage	I_{OL} = 16 mA, V_{CC} = Min V_{IN} = V_{IH} or V_{IL}			0.5	٧
Vıн	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0			V
Vıl	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)			0.8	٧
Іін	Input HIGH Leakage Current	$V_{IN} = 5.25 \text{ V}, V_{CC} = \text{Max (Note 2)}$			10	μΑ
I _{IL}	Input LOW Leakage Current	$V_{IN} = 0 V$, $V_{CC} = Max$ (Note 2)			-100	μΑ
Іоzн	Off-State Output Leakage Current HIGH	Vout = 5.25 V, Vcc = Max V _{IN} = V _{IH} or V _{IL} (Note 2)			10	μΑ
lozL	Off-State Output Leakage Current LOW	Vout = 0 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)			-100	μΑ
I _{sc}	Output Short-Circuit Current	$V_{OUT} = 0.5 \text{ V}, V_{CC} = \text{Max (Note 3)}$		-30	-130	mA
Icc	Supply Current (Typical)	$V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}, f = 25 \text{ MHz}$ (Note 4)		205		mA

- 1. These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.
- 2. I/O pin leakage is the worst case of I_IL and I_OZL (or I_IH and I_OZH).
- 3. Not more than one output should be shorted at a time and duration of the short-circuit should not exceed one second. $V_{OUT} = 0.5 \text{ V}$ has been chosen to avoid test problems caused by tester ground degradation.
- 4. Measured with a 12-bit up/down counter pattern. This pattern is programmed in each PAL block and is capable of being loaded, enabled, and reset.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditio	ns	Тур	Unit
CIN	Input Capacitance	V _{IN} = 2.0 V	$V_{CC} = 5.0 \text{ V}, T_A = 25^{\circ}\text{C},$	6	pF
Соит	Output Capacitance	V _{OUT} = 2.0 V	f = 1 MHz	8	pF

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter				-10	0	
Symbol	Parameter Description			Min	Max	Unit
t _{PD}	Input, I/O, o			10	ns	
	Setup Time	from Input, I/O,	D-type	6.5		ns
ts	or Feedback		T-type	7.5		ns
t _H	Register Da	ta Hold Time		0		ns
tco	Clock to Out	tput			6.0	ns
tw∟	Clock		LOW	4		ns
twн	Width		HIGH	4		ns
		Fortament For all and	D-type	80		MHz
	Maximum	External Feedback	T-type	74		MHz
f _{MAX}	Frequency		D-type	100		MHz
	(Note 1)	Internal Feedback (fcnt)	T-type	91		MHz
		No Feedback		125		MHz
t _{SL}	Setup Time	from Input, I/O, or Feedback to Gate		7		ns
t _{HL}	Latch Data I	0		ns		
t _{GO}	Gate to Out		7.5	ns		
t _{GWL}	Gate Width	4		ns		
t _{PDL}	Input, I/O, o	r Feedback to Output Through				
	Transparent		14	ns		
tsir	Input Regist	ter Setup Time		2		ns
t _{HIR}	Input Regist	ter Hold Time		2		ns
tico	Input Regist	ter Clock to Combinatorial Output			15	ns
t _{ICS}	Input Regist	ter Clock to Output Register Setup	D-type	11		ns
			T-type	12		ns
twicl	Input Regist	ter	LOW	4		ns
twich	Clock Width	l	HIGH	4		ns
f _{MAXIR}	Maximum In	nput Register Frequency		125		MHz
tsıL	Input Latch	Setup Time		2		ns
t _{HIL}	Input Latch	Hold Time		2		ns
t _{IGO}	Input Latch Gate to Combinatorial Output			17	ns	
tigoL	Input Latch Gate to Output Through Transparent Output Latch			18	ns	
tsll	Setup Time	from Input, I/O, or Feedback Through t Input Latch to Output Latch Gate		10		ns
tigs		Gate to Output Latch Setup		11		ns
	Impar Eaton Gate to Gatpar Eaton Getap					I



SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2) (continued)

Parameter		-1	0	1
Symbol	Parameter Description	Min	Max	Unit
t _{wigL}	Input Latch Gate Width LOW	4		ns
t _{PDLL}	Input, I/O, or Feedback to Output Through Transparent Input and Output Latches		16	ns
t _{AR}	Asynchronous Reset to Registered or Latched Output		15	ns
t _{ARW}	Asynchronous Reset Width (Note 1)	10		ns
t _{ARR}	Asynchronous Reset Recovery Time (Note 1)	8		ns
t _{AP}	Asynchronous Preset to Registered or Latched Output		15	ns
t _{APW}	Asynchronous Preset Width (Note 1)	10		ns
t _{APR}	Asynchronous Preset Recovery Time (Note 1)	8		ns
t _{EA}	Input, I/O, or Feedback to Output Enable		10	ns
t ER	Input, I/O, or Feedback to Output Disable		10	ns

- 1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.
- 2. See Switching Test Circuit, for test conditions.



ABSOLUTE MAXIMUM RATINGS

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

 $(T_A = 0^{\circ}C \text{ to } +70^{\circ}C) \dots 200 \text{ mA}$

OPERATING RANGES

Commercial (C) Devices

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Тур	Max	Unit
Vон	Output HIGH Voltage	I_{OH} = -3.2 mA, V_{CC} = Min V_{IN} = V_{IH} or V_{IL}	2.4			V
Vol	Output LOW Voltage	$I_{OL} = 16 \text{ mA}, V_{CC} = \text{Min}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$			0.5	V
V _{IH}	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0			V
V _{IL}	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)			0.8	V
I _{IH}	Input HIGH Leakage Current	V _{IN} = 5.25 V, V _{CC} = Max (Note 2)			10	μΑ
I₁∟	Input LOW Leakage Current	V _{IN} = 0 V, V _{CC} = Max (Note 2)			-100	μΑ
l _{OZH}	Off-State Output Leakage Current HIGH	V _{OUT} = 5.25 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)			10	μА
l _{OZL}	Off-State Output Leakage Current LOW	V _{OUT} = 0 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)			-100	μА
I _{SC}	Output Short-Circuit Current	V _{OUT} = 0.5 V, V _{CC} = Max (Note 3)		-30	-130	mΑ
Icc	Supply Current (Typical)	V _{CC} = 5 V, T _A = 25°C, f = 25 MHz (Note 4)		205		mA

- 1. These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.
- 2. I/O pin leakage is the worst case of I_{IL} and I_{OZL} (or I_{IH} and I_{OZH}).
- 3. Not more than one output should be shorted at a time and duration of the short-circuit should not exceed one second. $V_{OUT} = 0.5 \text{ V}$ has been chosen to avoid test problems caused by tester ground degradation.
- 4. Measured with a 12-bit up/down counter pattern. This pattern is programmed in each PAL block and is capable of being loaded, enabled, and reset.



CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Condition	ns	Тур	Unit
Cin	Input Capacitance	V _{IN} = 2.0 V	$V_{CC} = 5.0 \text{ V}, T_A = 25^{\circ}\text{C},$	6	pF
Соит	Output Capacitance	V _{OUT} = 2.0 V	f = 1 MHz	8	pF

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter	·			-1	2		15	-2	0		
Symbol	Parameter Description			Min	Max	Min	Max	Min	Max	Unit	
t _{PD}	Input, I/O, or	Feedback to Combination	atorial Output (N	Note 3)		12		15		20	ns
4-	Satus Tima f	from Input, I/O, or Fee	dhaak ta Claak	D-type	7		10		13		ns
ts	Setup Time i	Tom input, 1/O, or Fee	udack to Clock	T-type	8		11		14		ns
tн	Register Dat	a Hold Time			0		0		0		ns
tco	Clock to Out	put (Note 3)				8		10		12	ns
tw∟	Clock Width			LOW	6		6		8		ns
twн	Clock Width			HIGH	6		6		8		ns
		Fritament Fandbank	1/(t _S + t _{CO})	D-type	66.7		50		40		MHz
	Maximum	External Feedback	1/(15 + 100)	T-type	62.5		47.6		38.5		MHz
f _{MAX}	Frequency	Internal Feedback (f	CNT)	D-type	83.3		66.6		50		MHz
	(Note 1)	mieman ecaback (i	CNT	T-type	76.9		62.5		47.6		MHz
		No Feedback	1/(t _{WL} + t _{WH})		83.3		83.3		62.5		MHz
t _{SL}	Setup Time t	from Input, I/O, or Fee	dback to Gate		7		10		13		ns
t _H ∟	Latch Data Hold Time				0		0		0		ns
tgo	Gate to Output (Note 3)				10		11		12	ns	
t _{GWL}	Gate Width LOW			6		6		8		ns	
t _{PDL}	Input, I/O, or Feedback to Output Through Transparent Input or Output Latch				14		17		22	ns	
t _{SIR}	Input Register Setup Time			2		2		2		ns	
t _{HIR}	Input Registe	er Hold Time			2		2.5		3		ns
t _{ICO}	Input Registe	er Clock to Combinato	rial Output			15		18		23	ns
tics	Input Registe	er Clock to Output Reg	gister Setup	D-type	12		15		20		ns
				T-type	13		16		21		ns
twicl				LOW	6		6		8		ns
twich	Input Regist	er Clock Width		HIGH	6		6		8		ns
f _{MAXIR}	Maximum In	put Register Frequenc	cy 1/(t _{WICL} + t _V	исн)	83.3		83.3		62.5		MHz
tsıL	Input Latch S	Setup Time	•		2		2		2		ns
t _{HIL}	Input Latch H	Hold Time			2		2.5		3		ns
tigo	Input Latch (Gate to Combinatorial	Output			17		20		25	ns
tigoL	Input Latch Gate to Output Through Transparent Output Latch				19		22		27	ns	
tsll	Setup Time f Transparent	from Input, I/O, or Fee Input Latch to Output	dback Through Latch Gate		9		12		15		ns
t _{IGS}	Input Latch (Gate to Output Latch S	Setup		13		16		21		ns

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2) (continued)

Parameter		-1	2	-1	-15		-20	
Symbol	Parameter Description	Min	Max	Min	Max	Min	Max	Unit
twigL	Input Latch Gate Width LOW	6		6		8		ns
tpDLL	Input, I/O, or Feedback to Output Through Transparent Input and Output Latches		16		19		24	ns
t _{AR}	Asynchronous Reset to Registered or Latched Output		16		20		25	ns
tarw	Asynchronous Reset Width (Note 1)	12		15		20		ns
tarr	Asynchronous Reset Recovery Time (Note 1)	8		10		15		ns
tap	Asynchronous Preset to Registered or Latched Output		16		20		25	ns
tapw	Asynchronous Preset Width (Note 1)	12		15		20		ns
tapr	Asynchronous Preset Recovery Time (Note 1)	8		10		15		ns
tEA	Input, I/O, or Feedback to Output Enable (Note 3)		12		15		20	ns
ter	Input, I/O, or Feedback to Output Disable (Note 3)		12		15		20	ns

- 1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.
- See Switching Test Circuit for test conditions.
 Parameters measured with 24 outputs switching.



ABSOLUTE MAXIMUM RATINGS

Storage Temperature 65°C to +150°C
Ambient Temperature with Power Applied –55°C to +125°C
Supply Voltage with Respect to Ground0.5 V to +7.0 V
DC Input Voltage $-0.5~\text{V}$ to V _{CC} + 0.5 V
DC Output or I/O Pin Voltage0.5 V to V _{CC} + 0.5 V
Static Discharge Voltage 2001 V
Latchup Current $ (T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}) \ \dots \ 200 \text{ mA} $

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

INDUSTRIAL OPERATING RANGES

Ambient Temperature (T _A)	
Operating in Free Air	–40°C to +85°C
Supply Voltage (V _{CC}) with	
Respect to Ground	+4.5 V to +5.5 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over INDUSTRIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Тур	Max	Unit
Voн	Output HIGH Voltage	I_{OH} = -3.2 mA, V_{CC} = Min V_{IN} = V_{IH} or V_{IL}	2.4	,,		V
VoL	Output LOW Voltage	I _{OL} = 16 mA, V _{CC} = Min V _{IN} = V _{IH} or V _{IL}			0.5	V
V _{IH}	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0			٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)			0.8	V
I _{IH}	Input HIGH Leakage Current	V _{IN} = 5.25 V, V _{CC} = Max (Note 2)			10	μΑ
l₁∟	Input LOW Leakage Current	V _{IN} = 0 V, V _{CC} = Max (Note 2)			-100	μΑ
Іоzн	Off-State Output Leakage Current HIGH	V _{OUT} = 5.25 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)			10	μΑ
lozL	Off-State Output Leakage Current LOW	V _{OUT} = 0 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)			-100	μА
I _{SC}	Output Short-Circuit Current	V _{OUT} = 0.5 V, V _{CC} = Max (Note 3)	-30		-130	mA
Icc	Supply Current (Typical)	$V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}, f = 25 \text{ MHz (Note 4)}$		205		mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of I_{IL} and I_{OZL} (or I_{IH} and I_{OZH}).
- 3. Not more than one output should be shorted at a time. Duration of the short-circuit should not exceed one second. $V_{OUT} = 0.5 \text{ V}$ has been chosen to avoid test problems caused by tester ground degradation.
- 4. Measured with a 12-bit up/down counter pattern. This pattern is programmed in each PAL block and is capable of being loaded, enabled, and reset.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditio	ns	Тур	Unit
C _{IN}	Input Capacitance	$V_{IN} = 2.0 \text{ V}$	$V_{CC} = 5.0 \text{ V}, T_A = 25^{\circ}\text{C},$	6	pF
Соит	Output Capacitance	V _{OUT} = 2.0 V	f = 1 MHz	8	pF

SWITCHING CHARACTERISTICS over INDUSTRIAL operating ranges (Note 2)

Parameter			-1	4		18	-2	24			
Symbol	Parameter D	Description			Min	Max	Min	Max	Min	Max	Unit
t _{PD}	Input, I/O, or	Feedback to Combina	atorial Output (N	lote 3)		14.5		18		24	ns
				D-type	8.5		12		16		ns
ts	Setup Time f	Setup Time from Input, I/O, or Feedback to Clock T-type		T-type	10		13.5		17		ns
t _H	Register Dat	a Hold Time			0		0		0		ns
tco	Clock to Out	put (Note 3)				10		12		14.5	ns
tw∟	Clock Width			LOW	7.5		7.5		10		ns
twH	Olook Width			HIGH	7.5		7.5		10		ns
			1//ta ta a	D-type	53		40		32		MHz
	Maximum	External Feedback	1/(t _S + t _{CO})	T-type	50		38		30.5		MHz
f_{MAX}	Frequency	Internal Feedback (f	СИД	D-type	61.5		53		38		MHz
	(Note 1)	miomai i ocaback (i	Civi)	T-type	57		44		34.5		MHz
		No Feedback	1/(t _{WL} + t _{WH})		66.5		66.5		50		MHz
t _{SL}	Setup Time t	from Input, I/O, or Fee	dback to Gate		8.5		12		16		ns
t _{HL}	Latch Data F	lold Time			0		0		0		ns
t _{GO}	Gate to Outp	out (Note 3)				12		13.5		14.5	ns
t _{GWL}	Gate Width LOW		7.5		7.5		10		ns		
t _{PDL}	Input, I/O, or Feedback to Output Through Transparent Input or Output Latch			17		20.5		26.5	ns		
t _{SIR}	Input Register Setup Time		2.5		2.5		2.5		ns		
t _{HIR}	Input Register Hold Time		3		3.5		4		ns		
t _{ICO}	Input Registe	er Clock to Combinato	rial Output			18		22		28	ns
tics	Input Registe	er Clock to Output Reg	gister Setup	D-type	14.5		18		24		ns
				T-type	16		19.5		25.5		ns
twicL		OL 1 147 H		LOW	7.5		7.5		10		ns
twich	Input Regist	er Clock Width		HIGH	7.5		7.5		10		ns
f _{MAXIR}	Maximum In	put Register Frequenc	cy 1/(twicL+ tw	vic i)	66.5		66.5		50		MHz
t _{SIL}	Input Latch S	Setup Time			2.5		2.5		2.5		ns
t _{HIL}	Input Latch H	Hold Time			3		3.5		4		ns
tigo	Input Latch Gate to Combinatorial Output			20.5		24		30	ns		
tigoL	Input Latch Gate to Output Through Transparent Output Latch			23		26.5		32.5	ns		
t _{SLL}	Setup Time from Input, I/O, or Feedback Through Transparent Input Latch to Output Latch Gate		11		14.5		18		ns		
tıgs	Input Latch (Gate to Output Latch S	Setup		16		19.5		25.5		ns
twigL	Input Latch (Gate Width LOW			7.5		7.5		10		ns
t _{PDLL}		Feedback to Output 1 itput Latches	Through Transpa	arent		19.5		23		29	ns

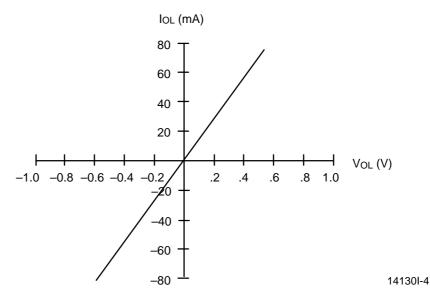


SWITCHING CHARACTERISTICS over INDUSTRIAL operating ranges (Note 2) (continued)

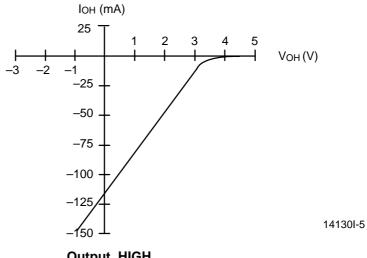
Parameter		-1	4	-18	3	-2	24	
Symbol	Parameter Description	Min	Max	Min	Max	Min	Max	Unit
t _{AR}	Asynchronous Reset to Registered or Latched Output		19.5		24		30	ns
t _{ARW}	Asynchronous Reset Width (Note 1)	14.5		18		24		ns
t _{ARR}	Asynchronous Reset Recovery Time (Note 1)	10		12		18		ns
t _{AP}	Asynchronous Preset to Registered or Latched Output		19.5		24		30	ns
t _{APW}	Asynchronous Preset Width (Note 1)	14.5		18		24		ns
t _{APR}	Asynchronous Preset Recovery Time (Note 1)	10		12		18		ns
t _{EA}	Input, I/O, or Feedback to Output Enable (Note 3)		14.5		18		24	ns
t _{ER}	Input, I/O, or Feedback to Output Disable (Note 3)		14.5		18		24	ns

- 1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where frequency may be affected.
 See Switching Test Circuit for test conditions.
 Parameters measured with 24 outputs switching.

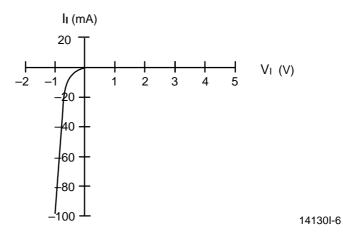
TYPICAL CURRENT VS. VOLTAGE (I-V) CHARACTERISTICS $V_{\text{CC}} = 5.0 \ \text{V}, \ T_{\text{A}} = 25^{\circ}\text{C}$



Output, LOW



Output, HIGH

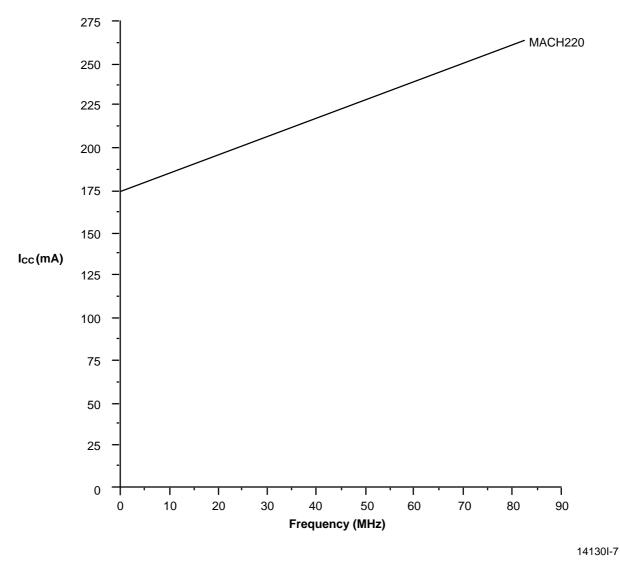


Input



TYPICAL Icc CHARACTERISTICS

 $V_{\text{CC}} = 5 \text{ V}, T_{\text{A}} = 25^{\circ}\text{C}$



The selected "typical" pattern is a 12-bit up/down counter. This pattern is programmed in each PAL block and is capable of being loaded, enabled, and reset.

Maximum frequency shown uses internal feedback and a D-type register.

TYPICAL THERMAL CHARACTERISTICS

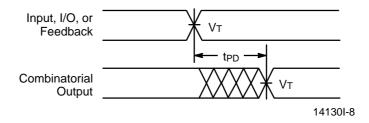
Measured at 25°C ambient. These parameters are not tested.

Parameter			Тур	
Symbol	Parameter Description			Units
θјс	Thermal impedance, junction to case			°C/W
θја	Thermal impedance, junction to ambient		33	°C/W
θjma	Thermal impedance, junction to	200 Ifpm air	29	°C/W
	ambient with air flow	400 lfpm air	27	°C/W
		600 Ifpm air	24	°C/W
		800 Ifpm air	23	°C/W

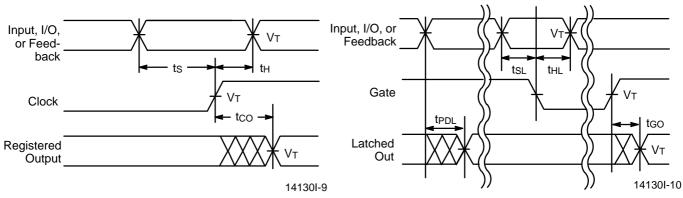
Plastic θ jc Considerations

The data listed for plastic θ ic are for reference only and are not recommended for use in calculating junction temperatures. The heat-flow paths in plastic-encapsulated devices are complex, making the θ ic measurement relative to a specific location on the package surface. Tests indicate this measurement reference point is directly below the die-attach area on the bottom center of the package. Furthermore, θ ic tests on packages are performed in a constant-temperature bath, keeping the package surface at a constant temperature. Therefore, the measurements can only be used in a similar environment.

SWITCHING WAVEFORMS

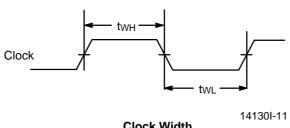


Combinatorial Output

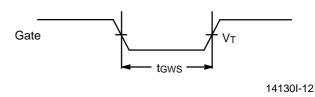


Registered Output

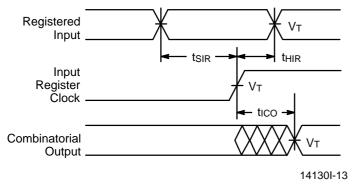
Latched Output (MACH 2, 3, and 4)



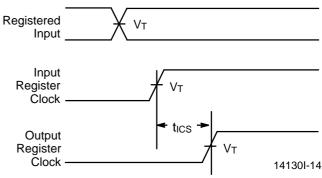
Clock Width



Gate Width (MACH 2, 3, and 4)



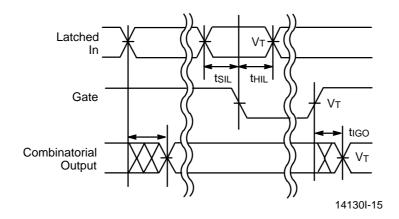
Registered Input (MACH 2 and 4)



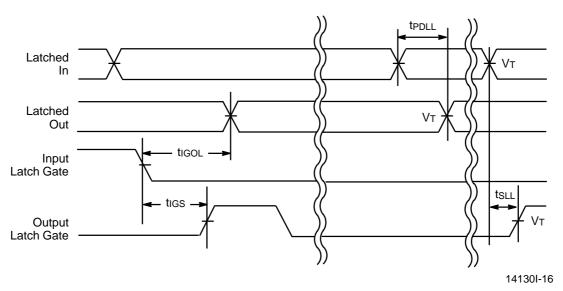
Input Register to Output Register Setup (MACH 2 and 4)

- 1. VT = 1.5 V.
- 2. Input pulse amplitude 0 V to 3.0 V.
- Input rise and fall times 2 ns-4 ns typical.

SWITCHING WAVEFORMS



Latched Input (MACH 2 and 4)

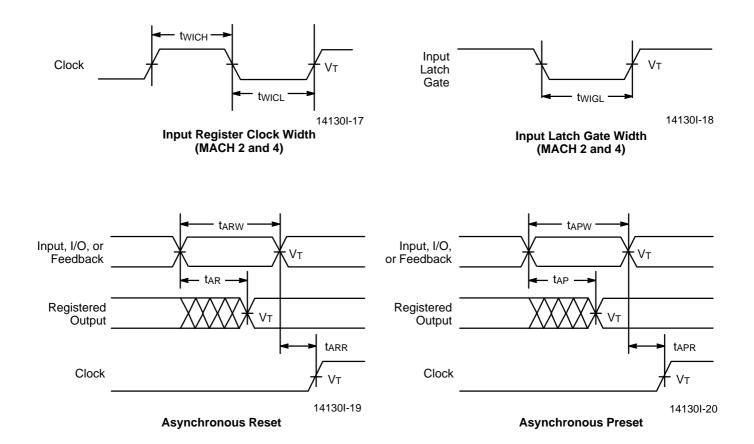


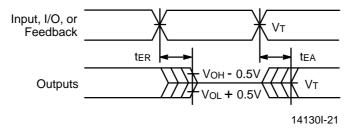
Latched Input and Output (MACH 2, 3, and 4)

- 1. VT = 1.5 V.
- Input pulse amplitude 0 V to 3.0 V.
 Input rise and fall times 2 ns-4 ns typical.



SWITCHING WAVEFORMS





Output Disable/Enable

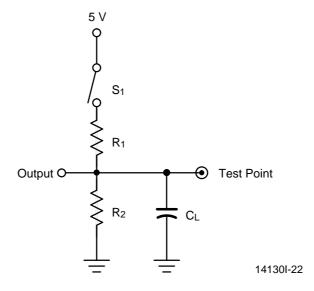
- 1. VT = 1.5 V.
- 2. Input pulse amplitude 0 V to 3.0 V.
- 3. Input rise and fall times 2 ns-4 ns typical.

KEY TO SWITCHING WAVEFORMS

WAVEFORM	INPUTS	OUTPUTS
	Must be Steady	Will be Steady
	May Change from H to L	Will be Changing from H to L
	May Change from L to H	Will be Changing from L to H
	Don't Care, Any Change Permitted	Changing, State Unknown
	Does Not Apply	Center Line is High- Impedance "Off" State

KS000010-PAL

SWITCHING TEST CIRCUIT



			Commercial		Measured
Specification	S ₁	C∟	R ₁	R ₂	Output Value
t _{PD} , t _{CO}	Closed				1.5 V
t _{EA}	$Z \rightarrow H$: Open $Z \rightarrow L$: Closed	35 pF	300 Ω	390 Ω	1.5 V
ter	$H \rightarrow Z$: Open $L \rightarrow Z$: Closed	5 pF			$H \rightarrow Z$: $V_{OH} - 0.5 V$ $L \rightarrow Z$: $V_{OL} + 0.5 V$

^{*}Switching several outputs simultaneously should be avoided for accurate measurement.

fMAX PARAMETERS

The parameter f_{MAX} is the maximum clock rate at which the device is guaranteed to operate. Because the flexibility inherent in programmable logic devices offers a choice of clocked flip-flop designs, f_{MAX} is specified for three types of synchronous designs.

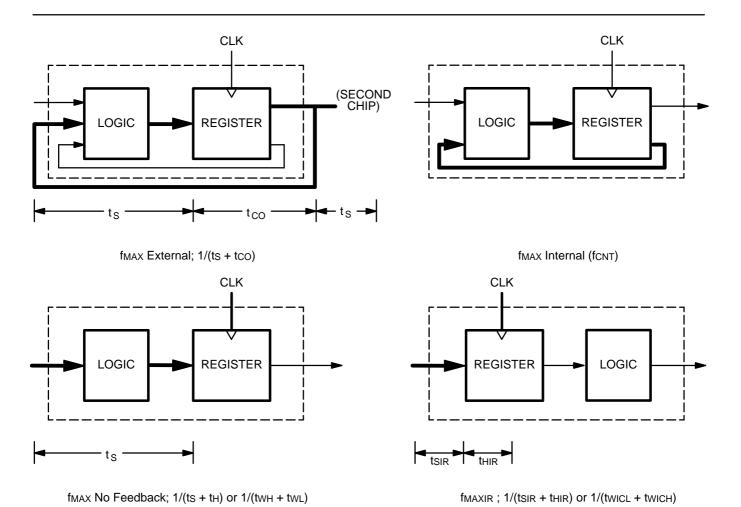
The first type of design is a state machine with feedback signals sent off-chip. This external feedback could go back to the device inputs, or to a second device in a multi-chip state machine. The slowest path defining the period is the sum of the clock-to-output time and the input setup time for the external signals ($t_s + t_{co}$). The reciprocal, t_{co} , is the maximum frequency with external feedback or in conjunction with an equivalent speed device. This t_{co} is designated " t_{co} flows external."

The second type of design is a single-chip state machine with internal feedback only. In this case, flip-flop inputs are defined by the device inputs and flip-flop outputs. Under these conditions, the period is limited by the internal delay from the flip-flop outputs through the internal feedback and logic to the flip-flop inputs. This f_{MAX} is designated " f_{MAX} internal". A simple internal counter is a good example of this type of design; therefore, this parameter is sometimes called " f_{CNT} ."

The third type of design is a simple data path application. In this case, input data is presented to the flip-flop and clocked through; no feedback is employed. Under these conditions, the period is limited by the sum of the data setup time and the data hold time ($t_S + t_H$). However, a lower limit for the period of each f_{MAX} type is the minimum clock period ($t_{WH} + t_{WL}$). Usually, this minimum clock period determines the period for the third f_{MAX} , designated " f_{MAX} no feedback."

For devices with input registers, one additional f_{MAX} parameter is specified: f_{MAXIR} . Because this involves no feedback, it is calculated the same way as f_{MAX} no feedback. The minimum period will be limited either by the sum of the setup and hold times ($t_{SIR} + t_{HIR}$) or the sum of the clock widths ($t_{WICL} + t_{WICH}$). The clock widths are normally the limiting parameters, so that f_{MAXIR} is specified as $1/(t_{WICL} + t_{WICH})$. Note that if both input and output registers are use in the same path, the overall frequency will be limited by t_{ICS} .

All frequencies except f_{MAX} internal are calculated from other measured AC parameters. f_{MAX} internal is measured directly.



ENDURANCE CHARACTERISTICS

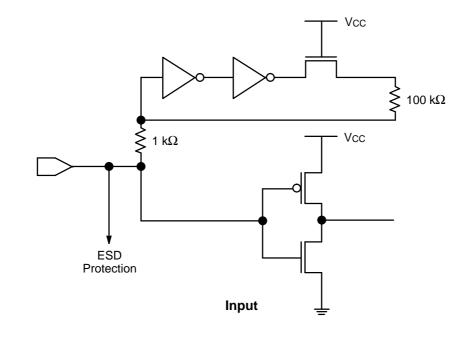
The MACH families are manufactured using AMD's advanced Electrically Erasable process. This technology uses an EE cell to replace the fuse link used in

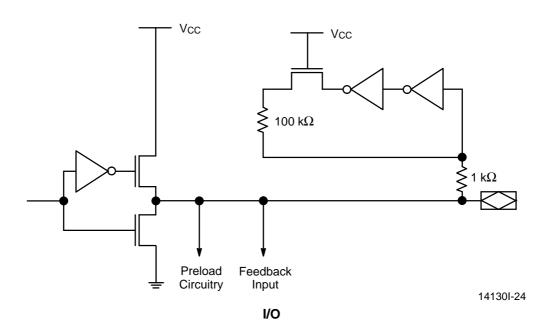
bipolar parts. As a result, the device can be erased and reprogrammed, a feature which allows 100% testing at the factory.

Endurance Characteristics

Parameter Symbol	Parameter Description	Min	Units	Test Conditions
		10	Years	Max Storage Temperature
t _{DR}	Min Pattern Data Retention Time	20	Years	Max Operating Temperature
N	Max Reprogramming Cycles	100	Cycles	Normal Programming Conditions

INPUT/OUTPUT EQUIVALENT SCHEMATICS





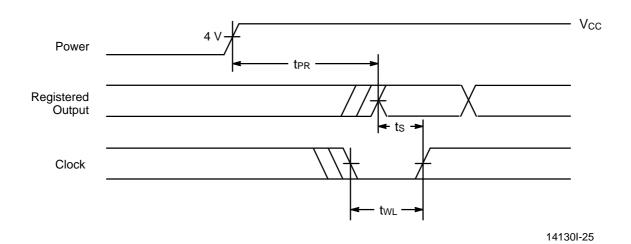
POWER-UP RESET

The MACH devices have been designed with the capability to reset during system power-up. Following power-up, all flip-flops will be reset to LOW. The output state will depend on the logic polarity. This feature provides extra flexibility to the designer and is especially valuable in simplifying state machine initialization. A timing diagram and parameter table are shown below. Due to the synchronous operation of the power-up reset and the

wide range of ways V_{CC} can rise to its steady state, two conditions are required to insure a valid power-up reset. These conditions are:

- 1. The V_{CC} rise must be monotonic.
- 2. Following reset, the clock input must not be driven from LOW to HIGH until all applicable input and feedback setup times are met.

Parameter Symbol	Parameter Descriptions	Max	Unit
t _{PR}	Power-Up Reset Time	10	μs
ts	Input or Feedback Setup Time	See	
tw∟	Clock Width LOW	Switching Characteris	tics



Power-Up Reset Waveform



USING PRELOAD AND OBSERVABILITY

In order to be testable, a circuit must be both controllable and observable. To achieve this, the MACH devices incorporate register preload and observability.

In preload mode, each flip-flop in the MACH device can be loaded from the I/O pins, in order to perform functional testing of complex state machines. Register preload makes it possible to run a series of tests from a known starting state, or to load illegal states and test for proper recovery. This ability to control the MACH device's internal state can shorten test sequences, since it is easier to reach the state of interest.

The observability function makes it possible to see the internal state of the buried registers during test by overriding each register's output enable and activating the output buffer. The values stored in output and buried registers can then be observed on the I/O pins. Without this feature, a thorough functional test would be impossible for any designs with buried registers.

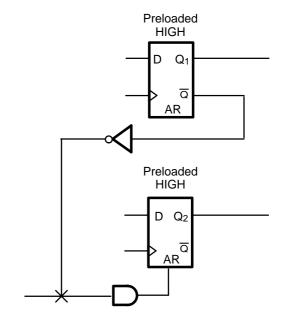
While the implementation of the testability features is fairly straightforward, care must be taken in certain instances to insure valid testing.

One case involves asynchronous reset and preset. If the MACH registers drive asynchronous reset or preset lines and are preloaded in such a way that reset or preset are asserted, the reset or preset may remove the preloaded data. This is illustrated in Figure 2. Care should be taken when planning functional tests, so that states that will cause unexpected resets and presets are not preloaded.

Another case to be aware of arises in testing combinatorial logic. When an output is configured as combinatorial, the observability feature forces the output into registered mode. When this happens, all product terms are forced to zero, which eliminates all combinatorial data. For a straight combinatorial output, the correct value will be restored after the preload or observe function, and there will be no problem. If the function implements a combinatorial latch, however, it relies on feedback to hold the correct value, as shown in Figure 3. As this value may change during the preload or observe operation, you cannot count on the data being correct after the operation. To insure valid testing in these cases, outputs that are combinatorial latches should not be tested immediately following a preload or observe sequence, but should first be restored to a known state.

All MACH 2 devices support both preload and observability.

Contact individual programming vendors in order to verify programmer support.



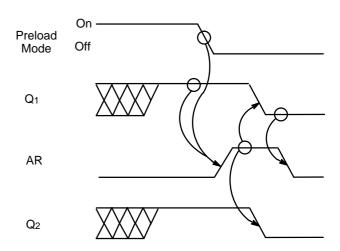


Figure 2. Preload/Reset Conflict

14130I-26

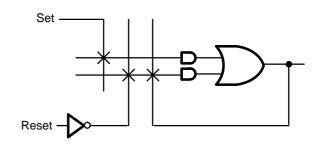


Figure 3. Combinatorial Latch

14130I-27

DEVELOPMENT SYSTEMS (subject to change)

For more information on the products listed below, please consult the AMD FusionPLD Catalog.

MANUFACTURER	SOFTWARE DEVELOPMENT SYSTEMS
Advanced Micro Devices, Inc. P.O. Box 3453, MS 1028 Sunnyvale, CA 94088-3543 (800) 222-9323 or (408) 732-2400	MACHXL [®] Software Ver. 2.0
Advanced Micro Devices, Inc. P.O. Box 3453, MS 1028 Sunnyvale, CA 94088-3543 (800) 222-9323 or (408) 732-2400	Design Center/AMD Software
Advanced Micro Devices, Inc. P.O. Box 3453, MS 1028 Sunnyvale, CA 94088-3543 (800) 222-9323 or (408) 732-2400	AMD-ABEL Software Data I/O MACH Fitters
Advanced Micro Devices, Inc. P.O. Box 3453, MS 1028 Sunnyvale, CA 94088-3543 (800) 222-9323 or (408) 732-2400	PROdeveloper/AMD Software PROsynthesis/AMD Software
Cadence Design Systems 555 River Oaks Pkwy San Jose, CA 95134 (408) 943-1234	ComposerPIC TM Designer (Requires MACH Fitter) Verilog, LeapFrog, RapidSim Simulators (Models also available from Logic Modeling) Ver. 3.3
Capilano Computing 960 Quayside Dr., Suite 406 New Westminster, B.C. Canada V3M 6G2 (800) 444-9064 or (604) 552-6200	MacABEL™ Software (Requires SmartPart MACH Fitter)
CINA, Inc. P.O. Box 4872 Mountain View, CA 94040 (415) 940-1723	SmartCAT Circuit Analyzer
Data I/O Corporation 10525 Willows Road N.E. P.O. Box 97046 Redmond, WA 98073-9746 (800) 332-8246 or (206) 881-6444	ABEL™-5 Software (Requires MACH Fitter) Synario™ Software
iNt GmbH Busenstrasse 6 D-8033 Martinsried, Munich, Germany (89) 857-6667	PLDSim 90
ISDATA GmbH Daimlerstr. 51 D7500 Karlsruhe 21 Germany Germany: 0721/75 10 87 U.S.: (510) 531-8553	LOG/iC™ Software (Requires MACH Fitter)
Logic Modeling 19500 NW Gibbs Dr. P.O. Box 310 Beaverton, OR 97075 (503) 690-6900	SmartModel [®] Library
Logical Devices, Inc. 692 S. Military Trail Deerfield Beach, FL 33442 (800) 331-7766 or (305) 428-6868	CUPL™ Software



DEVELOPMENT SYSTEMS (subject to change) (continued)

MANUFACTURER	SOFTWARE DEVELOPMENT SYSTEMS		
Mentor Graphics Corp. 8005 S.W. Boeckman Rd. Wilsonville, OR 97070-7777 (800) 547-3000 or (503) 685-7000	PLDSynthesis™ (Requires MACH Fitter) QuickSim Simulator (Models also available from Logic Modeling)		
MicroSim Corp. 20 Fairbanks Irvine, CA 92718 (714) 770-3022	Design Center Software (Requires MACH Fitter)		
MINC Incorporated 6755 Earl Drive, Suite 200 Colorado Springs, CO 80918 (800) 755-FPGA or (719) 590-1155	PLDesigner™-XL Software (Requires MACH Fitter)		
OrCAD 3175 N.W. Aloclek Dr. Hillsboro, OR 97124 (503) 690-9881	Programmable Logic Design Tools 386+ Schematic Design Tool 386+ Digital Simulation Tools		
SUSIE-CAD 10000 Nevada Highway, Suite 201 Boulder City, NV 89005 (702) 293-2271	SUSIE [™] Simulator		
Teradyne EDA 321 Harrison Ave. Boston, MA 02118 (800) 777-2432 or (617) 422-2793	MultiSIM Interactive Simulator LASAR		
Viewlogic Systems, Inc. 293 Boston Post Road West Marlboro, MA 01752 (800) 442-4660 or (508) 480-0881	ViewPLD or PROPLD (Requires PROSim Simulator MACH Fitter) ViewSim Simulator (Models for ViewSim also available from Logic Modeling)		
MANUFACTURER	TEST GENERATION SYSTEM		
Acugen Software, Inc. 427-3 Amherst St., Suite 391 Nashua, NH 03063 (603) 891-1995	ATGEN™ Test Generation Software		
iNt GmbH Busenstrasse 6 D-8033 Martinsried, Munich, Germany (87) 857-6667	PLDCheck 90		

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APPROVED PROGRAMMERS (subject to change)

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MANUFACTURER	PRO	GRAMMER CONFIGURATI	ON
Advin Systems, Inc. 1050-L East Duane Ave. Sunnyvale, CA 94086 (408) 243-7000		Pilot U84	
BP Microsystems 100 N. Post Oak Rd. Houston, TX 77055-7237 (800) 225-2102 or (713) 688-4600		BP1200	
Data I/O Corporation 10525 Willows Road N.E. P.O. Box 97046 Redmond, WA 98073-9746 (800) 332-8246 or (206) 881-6444	UniSite™	Model 3900	AutoSite
Logical Devices Inc./Digelec 692 S. Military Trail Deerfield Beach, FL 33442 (800) 331-7766 or (305) 428-6868		ALLPRO™–88	
SMS North America, Inc. 16522 NE 135th Place Redmond, WA 98052 (800) 722-4122 or SMS Im Grund 15 D-7988 Vangen Im Allgau, Germany 07522-5018		Sprint/Expert	
Stag Microsystems Inc. 1600 Wyatt Dr. Suite 3 Santa Clara, CA 95054 (408) 988-1118 or Stag House Martinfield, Welwyn Garden City Herfordshire UK AL7 1JT 707-332148		Stag Quazar	
System General 510 S. Park Victoria Dr. Milpitas, CA 95035 (408) 263-6667 or 3F, No. 1, Alley 8, Lane 45 Bao Shing Rd., Shin Diau Taipei, Taiwan 2-917-3005		Turpro-1	

APPROVED ON-BOARD PROGRAMMERS

MANUFACTURER	PROGRAMMER CONFIGURATION	
Corelis, Inc. 12607 Hidden Creek Way, Suite H Cerritos, California 70703 (310) 926-6727	JTAG PROG	
Advanced Micro Devices P.O. Box 3453, MS-1028 Sunnyvale, CA 94088-3453 (800) 222-9323	MACHpro	



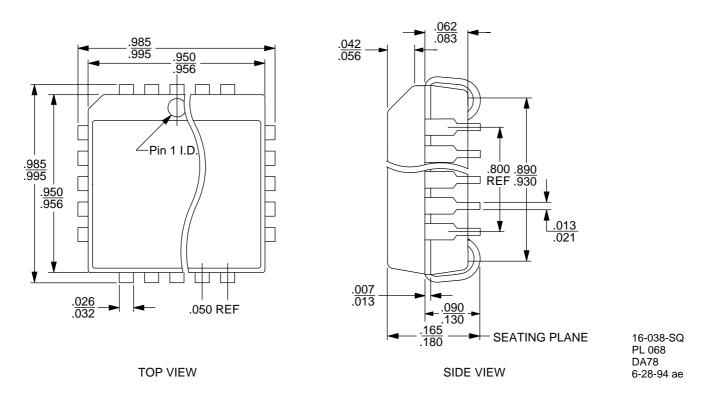
PROGRAMMER SOCKET ADAPTERS (subject to change)

MANUFACTURER	PART NUMBER
EDI Corporation P.O. Box 366 Patterson, CA 95363 (209) 892-3270	Contact Manufacturer
Emulation Technology 2344 Walsh Ave., Bldg. F Santa Clara, CA 95051 (408) 982-0660	Contact Manufacturer
Logical Systems Corp. P.O. Box 6184 Syracuse, NY 13217-6184 (315) 478-0722	Contact Manufacturer
Procon Technologies, Inc. 1333 Lawrence Expwy, Suite 207 Santa Clara, CA 95051 (408) 246-4456	Contact Manufacturer

PHYSICAL DIMENSIONS*

PL 068

68-Pin Plastic Leaded Chip Carrier (measured in inches)



^{*}For reference only. BSC is an ANSI standard for Basic Space Centering.

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